

UTC UNISONIC TECHNOLOGIES CO., LTD

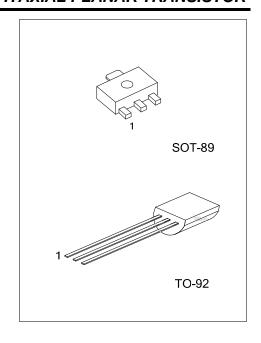
2N3906

PNP EPITAXIAL PLANAR TRANSISTOR

GENERAL PURPOSE APPLIATION

FEATURES

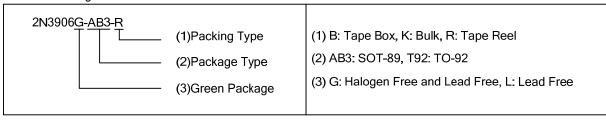
- * Collector-Emitter Voltage: V_{CEO}=40V
- * Complementary to UTC 2N3904



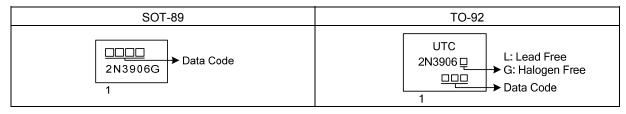
ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
-	2N3906G-AB3-R	SOT-89	В	С	E	Tape Reel	
2N3906L-T92-B	2N3906G-T92-B	TO-92	Е	В	С	Tape Box	
2N3906L-T92-K	2N3906G-T92-K	TO-92	Е	В	С	Bulk	

Pin Assignment: B: Base E: Emitter Note: C: Collector



MARKING



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■ ABSOLUTE MAXIMUM RATING (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT	
Collector-Base Voltage		V_{CBO}	-40	V	
Collector-Emitter Voltage		V_{CEO}	-40	V	
Emitter-Base Voltage		V_{EBO}	-5	V	
Collector Current		I _C	-200	mA	
Base Current		Ι _Β	-50	mA	
Collector dissipation	SOT-89	Pc	550	\^/	
	TO-92		625	mW	
Junction Temperature		Τ _J	125	°C	
Operating Temperature		T _{OPR}	-20 ~ +85	°C	
Storage Temperature		T _{STG}	-40 ~ +150	°C	

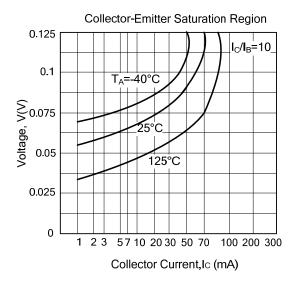
Note: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

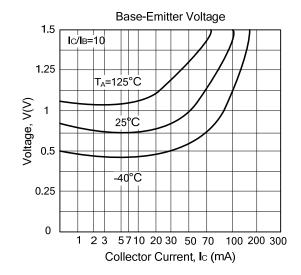
■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise specified)

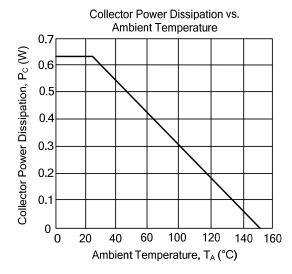
PARAMETER	SYMBOL	TEST CONDITIONS		TYP	MAX	UNIT	
Collector Cut-Off Current	I _{CEX}	V _{CE} =-30V, V _{EB} =-3V			-50	nA	
Base Cut-Off Current	I_{BL}	V_{CE} =-30V, V_{EB} =-3V			-50	nA	
Collector-Base Breakdown Voltage	V_{CBO}	I _C =-10μA, I _E =0	-40			V	
Collector-Emitter Breakdown Voltage	V_{CEO}	I _C =-1mA, I _B =0 (Note)	-40			V	
Emitter-Base Breakdown Voltage	V_{EBO}	$I_E=-10\mu A, I_C=0$	-6			V	
DC Current Gain (Note)	h _{FE1}	V_{CE} =-1V, I_{C} =-0.1mA					
	h _{FE2}	V _{CE} =-1V, I _C =-1mA	80				
	h _{FE3}	V_{CE} =-1V, I_{C} =-10mA	100		300		
	h _{FE4}	V_{CE} =-1V, I_{C} =-50mA	60				
	h _{FE5}	V _{CE} =-1V, I _C =-100mA	30				
Collector-Emitter Saturation Voltage	$V_{CE(SAT)1}$	I _C =-10mA, I _B =-1mA			-0.25	V	
(Note)	$V_{CE(SAT)2}$	I_C =-50mA, I_B =-5mA			-0.4	V	
Dago Fraittes Caturation Valtage	$V_{BE(SAT)1}$	I _C =-10mA, I _B =-1mA	-0.65		-0.85	V	
Base-Emitter Saturation Voltage	$V_{\text{BE}(\text{SAT})2}$	I_C =-50mA, I_B =-5mA			-0.95	V	
Transition Voltage	f_{T}	V _{CE} =-20V, I _C =-10mA, f=100MHz	250			MHz	
Output Capacitance	Сов	V _{CB} =-5V, I _E =0, f=1MHz			4.5	pF	
Turn On Time	t _{ON}	V_{CC} =-3V, V_{BE} =-0.5V, I_{C} =-10mA, I_{B1} =-1mA			70	ns	
Turn Off Time	t _{OFF}	I _{B1} =1 _{B2} =-1mA			300	ns	

Note: Pulse test: P_W <=300 μ s, Duty Cycle<=2%

■ TYPICAL CHARACTERISTICS







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